

# 6A, 200V - 600V Ultra Fast Surface Mount Rectifier

#### **FEATURES**

- Very low profile, typical height of 1.1mm
- Excellent high temperature stability
- Glass passivated chip junction
- Controlled avalanche characteristics
- Low leakage current
- High forward surge capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

#### **APPLICATIONS**

- DC to DC converter
- Switching mode converters and inverters
- Freewheeling application

### **MECHANICAL DATA**

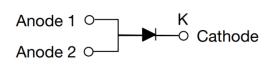
- Case: TO-277A (SMPC)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: Indicated by cathode band
- Weight: 0.095g (approximately)

KEY PARAMETERS			
PARAMETER VALUE UN			
I <sub>F</sub>	6	А	
V <sub>RRM</sub>	200 - 600	V	
I <sub>FSM</sub>	80	А	
T <sub>J MAX</sub>	175	°C	
Package	TO-277A (SMPC)		
Configuration	Single die		





TO-277A (SMPC)



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)				
PARAMETER	SYMBOL	TPUH6D	TPUH6J	UNIT
Marking code on the device		UH6D	UH6J	
Repetitive peak reverse voltage	V <sub>RRM</sub>	200	600	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	140	420	V
Forward current	I <sub>F</sub>		6	А
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I <sub>FSM</sub>	8	0	А
Junction temperature	TJ	-55 tc	) +175	°C
Storage temperature	T <sub>STG</sub>	-55 tc	) +175	°C



THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Junction-to-lead thermal resistance <sup>(1)</sup>	$R_{\Theta JL}$	12	°C/W	
Junction-to-ambient thermal resistance <sup>(2)</sup>	R <sub>eja</sub>	80	°C/W	

Notes:

- 1. Mounted on FR4 PCB with 16mm x 16mm Cu pad area
- 2. Free air, mounted on recommended pad

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^{\circ}C$ unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
	TPUH6D	I <sub>F</sub> = 3A, T <sub>J</sub> = 25°C		0.80	-	V
	TPUH6J			1.98	-	V
	TPUH6D	I <sub>F</sub> = 6A, T <sub>J</sub> = 25°C	V <sub>F</sub>	0.87	1.05	V
(1)	TPUH6J			2.45	3.00	V
Forward voltage <sup>(1)</sup>	TPUH6D	I <sub>F</sub> = 3A, T <sub>J</sub> = 125°C		0.65	-	V
	TPUH6J			1.23	-	V
	TPUH6D	I <sub>F</sub> = 6A, T <sub>J</sub> = 125°C		0.73	0.90	V
	TPUH6J			1.59	1.80	V
Reverse current @ rated V <sub>R</sub> <sup>(2)</sup>		T <sub>J</sub> = 25°C	I <sub>R</sub>	-	10	μA
		T <sub>J</sub> = 125°C		-	200	μA
Junction capacitance		1MHz, V <sub>R</sub> = 4.0V	CJ	50	-	pF
Reverse recovery time		IF = 0.5A, IR = 1.0A Irr = 0.25A	t <sub>rr</sub>	-	25	ns
		$I_F = 1A$ , di/dt = -50A/µs $V_R = 30V$	t <sub>rr</sub>	-	45	ns

#### Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

## ORDERING INFORMATION

ORDERING CODE <sup>(1)</sup>	PACKAGE	PACKING
TPUH6x	TO-277A (SMPC)	6,000 / Tape & Reel

Notes:

1. "x" defines voltage from 200V(TPUH6D) to 600V(TPUH6J)



## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

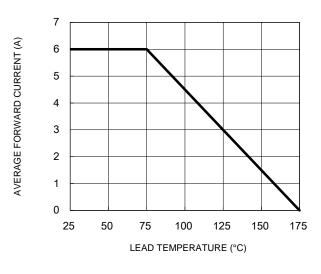
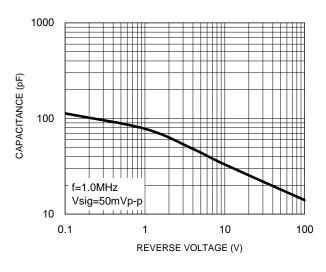


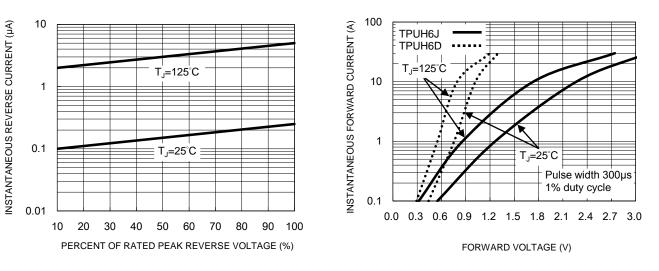
Fig.1 Forward Current Derating Curve

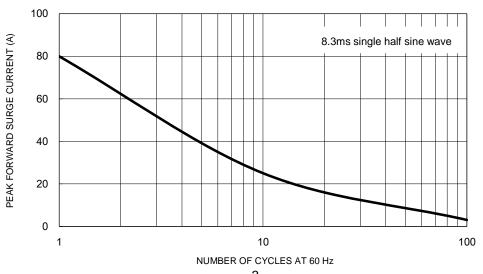
#### **Fig.3 Typical Reverse Characteristics**



#### **Fig.2 Typical Junction Capacitance**

**Fig.4 Typical Forward Characteristics** 



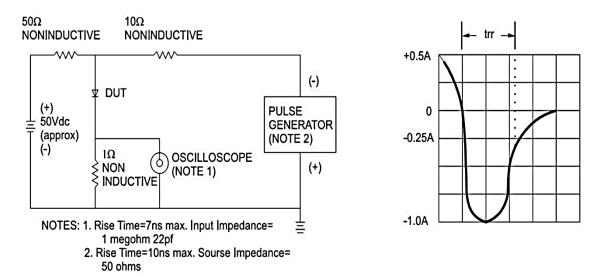


#### Fig.5 Maximum Non-Repetitive Forward Surge Current



## **CHARACTERISTICS CURVES**

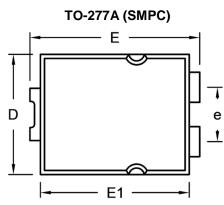
 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

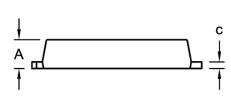


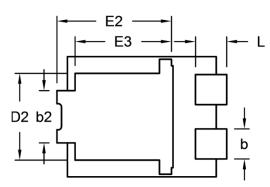
#### Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram

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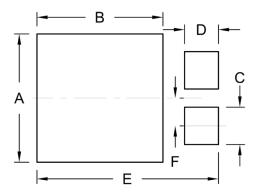




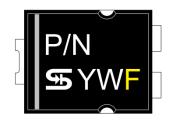


DIM.	Unit (mm)		Unit (mm)		Unit (	Unit (inch)	
	Min.	Max.	Min.	Max.			
A	1.000	1.200	0.039	0.047			
b	1.000	1.300	0.039	0.051			
b2	1.850	2.150	0.073	0.085			
с	0.175	0.325	0.007	0.013			
D	4.550	4.650	0.179	0.183			
D2	3.170	3.470	0.125	0.137			
E	6.350	6.650	0.250	0.262			
E1	5.650	5.750	0.222	0.226			
E2	4.235	4.535	0.167	0.179			
E3	3.540	3.840	0.139	0.151			
е	1.930	2.230	0.076	0.088			
L	1.043	1.343	0.041	0.053			

SUGGESTED PAD LAYOUT



**MARKING DIAGRAM** 



Symbol	Unit (mm)	Unit (inch)
А	4.80	0.189
В	4.72	0.186
С	1.40	0.055
D	1.27	0.050
E	6.80	0.268
F	1.04	0.041

P/N = Marking Code

YW = Date Code

F = Factory Code



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